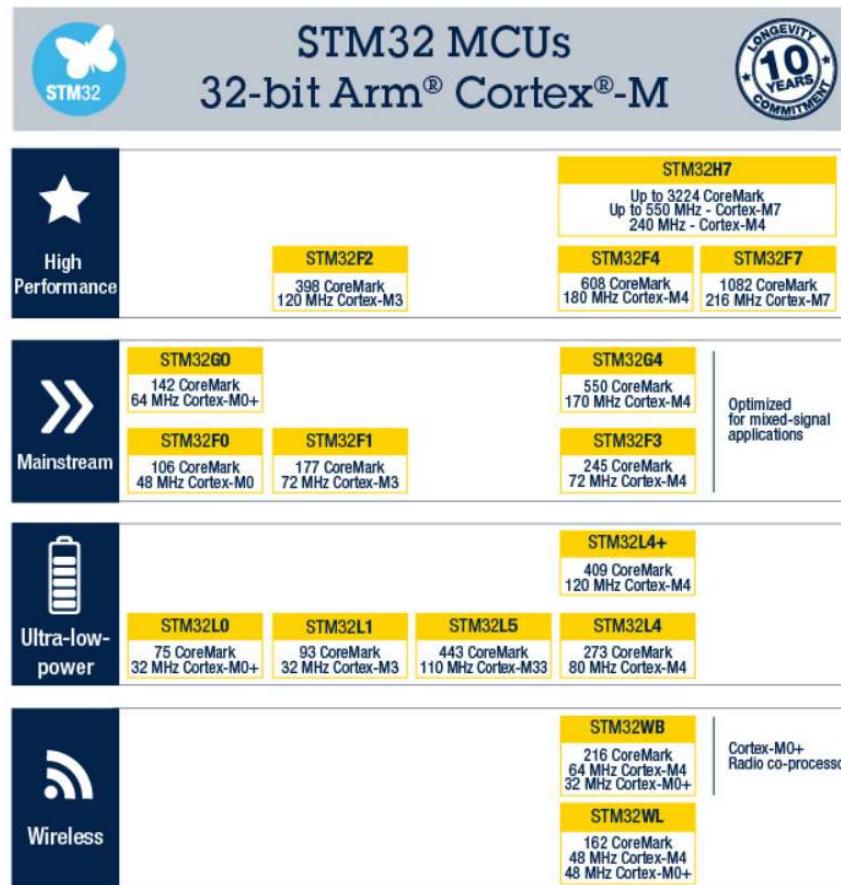


Considerations When Designing Crystals into STM32 Microcontrollers

1. STM32 processor families (Ref: #1)

Table 1 shows the range of STM32 processor families and how they have been matched to different application verticals. Picking the desired MCU family is obviously the first choice a designer must consider. Some of these choices are outside the remit of this paper, like clocking speed, internal architecture and memory levels that impact the overall design. Power level of the architecture is the key factor for the oscillator design that follows. The designer's choice at this stage to use an ultra-low power processor will have a major impact later in the design of the oscillator loop. Many of the STM32 MCU's offer a variable drive level. These offer designers LSE oscillators with modifiable on the fly transconductance (dynamically) like the STM32L0 and others in this category. Other MCU's like STM32L1, or F4, are fixed drive levels, and may have less flexibility (Ref #2 page 22).

Table 1 – STM32MCUs



STM32 MCUs
32-bit Arm® Cortex®-M

**LONGEVITY
10 YEARS
COMMITMENT**

	STM32H7			
	STM32F2	STM32F4	STM32F7	
High Performance	398 CoreMark 120 MHz Cortex-M3	608 CoreMark 180 MHz Cortex-M4	1082 CoreMark 216 MHz Cortex-M7	
Mainstream	STM32G0 142 CoreMark 64 MHz Cortex-M0+	STM32G4 550 CoreMark 170 MHz Cortex-M4	STM32F3 245 CoreMark 72 MHz Cortex-M4	Optimized for mixed-signal applications
	STM32F0 106 CoreMark 48 MHz Cortex-M0	STM32F1 177 CoreMark 72 MHz Cortex-M3		
Ultra-low-power	STM32L0 75 CoreMark 32 MHz Cortex-M0+	STM32L1 93 CoreMark 32 MHz Cortex-M3	STM32L5 443 CoreMark 110 MHz Cortex-M33	STM32L4+ 409 CoreMark 120 MHz Cortex-M4
Wireless			STM32WB 216 CoreMark 64 MHz Cortex-M4 32 MHz Cortex-M0+ STM32WL 162 CoreMark 48 MHz Cortex-M4 48 MHz Cortex-M0+	Cortex-M0+ Radio co-processor

2. What overall considerations should a designer look at when choosing a crystal?

- Will the crystal meet design guidelines and operate as planned?
- Will the crystal oscillator meet the power drain needs of the application?
- Will the crystal size fit the applications needs; is it small enough, lower drive or AEC-Q200?
- Will the crystal meet the cost targets set by the design?

ECS Inc have created a tool that makes these choices easier to bring together. The tool has been specifically designed for the range of STM32 MCU's.

See link: [STM32 MCU Series LSE 32.768KHz Crystal Selection Tool](#)

3. Spec parameters that impact SMT32 MCU crystal oscillator design

- a. Start-up - Start-up performance can be looked at in two ways; firstly, if the oscillator will start-up consistently in the application under environmental conditions, and secondly how long it takes to start-up at power up. The data sheet parameters that affect start-up are CL, ESR and C0. Making any of these lower improves gain margin that improves start-up. A greater depth explanation is discussed in Section 5 that cover Gain Margin.

Figure 1 – Oscillator Start-up

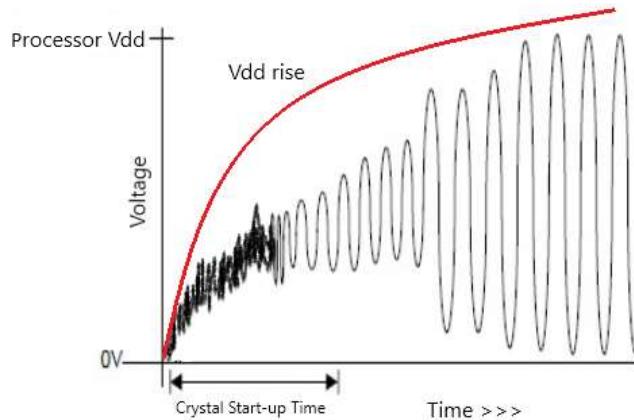
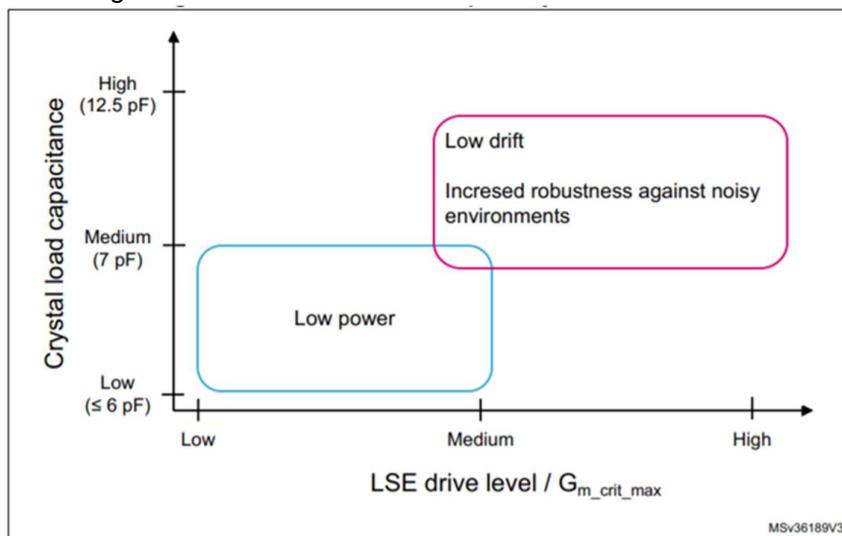


Figure 1 shows a typical Vdd rise from 0V and how oscillator closed loop gain increases until unity gain is reached, and the oscillator loop stabilizes, locking onto the resonator frequency. The time from 0V to start-up of stable oscillation is shown a Start-up time.

- b. Cost - Mass production volumes impact the global market for all BOM items that make up a crystal resonator. The 3.2 x 1.5 mm size is currently the largest volume seller, so we see prices very competitive in this size. ECS has the largest selection in this size as STM32 Reference Designs, with 20 options (Ref #2 page 36). The trend is towards smaller sizes are generally with 2.0 x 1.2 mm the next used option. Cost increases with further package size reduction.
- c. Package Size - As mentioned above the trend is for smaller package sizes, as driven by mobile wireless solutions. ECS Inc offers the widest selection of watch crystals in the industry with referenced part numbers for all STM32 MCU's. These range from 1.2 x 1.0 mm to 8.0 x 3.8 mm. Different package sizes offer different constraints, one of the major parameters is the ESR. Due to the crystal blank size, the ESR increases as package size reduces, this in turn impacts the gm_crit of the crystal. The ESC Selection Tool helps here, allowing the designer to make these considerations.
- d. Tolerance – Most designs will look for a standard 20ppm tolerance crystal; tolerance is the manufacturing measured ppm range at 25°C. In some applications, tighter tolerance is important, and this is again where the ECS selection Tool helps to narrow the range of options.

- e. Drive Level – Drive level is an important parameter to meet at both ends of the spectrum. Too low and the crystal won't start-up, too high and the crystal could be damaged or the oscillator loop saturate, so that loop gain drops <1 and the oscillator could stop.
 - i. Low Drive - The ECS Selection Tool lists all parts that have a Gain Margin of 5 or greater for the specific STM32 processor with the selected or standard drive level. This ensures the crystal will start-up and is the first priority. The ECS Selection Tool helps the designer to meet this mandatory requirement, but then allows you to explore options. Picking a lower gm_{crit} actual will mean a lower drive current through the crystal, so using less power.
 - ii. High Drive - The other extreme is more drive than the crystal and the oscillator loop can withstand. Some of the STM32 MCU's have a HIGH DRIVE configurable setting, for these its recommended to use 12.5pF CL crystal.

Figure 2 – Consideration for Drive level STM32 MCU's (Ref #2 page 20)



- iii. Figure 2 above taken from the STM32 AN2867 (Ref #2 page 20), shows some of the compromises to consider when using different drive levels. Often low power is the driving factor for handheld or wireless connected applications. The graph shows selecting 6pF or less CL with medium to low drive levels is a starting point for these applications. The ECS selection Tool helps refine this; by selecting for example F0 Medium Low, the range of CL from 6pF to 4pF can be selected (Ctrl + Select). Then further refinement can be made selecting Size and ESR to find the best solution.
- iv. Remembering lower CL values result in increased pullability. Therefore, design variance like capacitor tolerance could lead to less accuracy or more variability in production. These lower CL crystals are also more vulnerable to noisy environments. ECS offers some of the lowest ESR's in the industry, if this is suitable workaround.

- v. If low power is not a driving factor, a higher CL value will give more robustness to noisy environments. In these cases where MCU high drive is implemented a 12.5pF CL is advised. This will make the oscillator closed loop less vulnerable to saturation. This saturation situation occurs as the sine wave approaches the supply rails, the amplifier in the closed loop flattens (clips) the sine peaks, suddenly small signal gain instantaneously drops to zero. This only recovers when the output amplitude increases until the nonlinearity reduces the average small signal gain to one, so oscillation can continue. Remember, Barkhausen Criterion, where first condition is that the magnitude of the loop gain ($A\beta$) must be unity.
- vi. So overdriving is an issue for the stability of the oscillations and is manifested in no oscillation or high jitter. Equally we need to consider drive through the crystal. The spec will detail the max drive level, and testing should be done to see these criteria are not exceeded.
- f. AEC-Q200 options – Automotive grade (AEC-Q200) is another often mandatory option that is required when the designer is making the crystal selection. ECS has a wide range of spec options available in package size 2.0 x 1.2 mm (12Q series) and 3.2 x 15 mm (34Q series). Some of these again can be found using the ECS Selection Tool, but a wider selection is also available in Distribution. If any help is needed to understand the gm_crit of these parts ECS will be pleased to help.

4. Oscillator loop terminology explained

**Pierce Oscillator Loop showing
Caps and resistors**

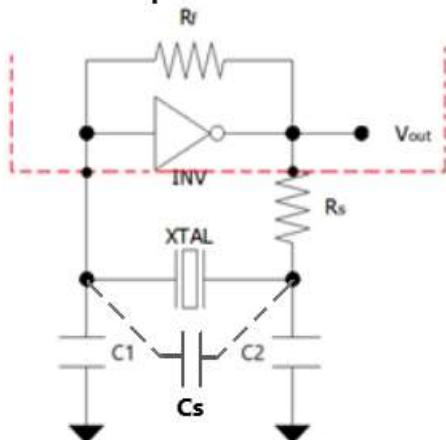


Figure 3 – Pierce Oscillator Loop

Figure 3 shows a typical Pierce Oscillator loop and is common to STM32 MCU LSE crystal oscillators.

- a. Inv: the internal inverter that works as an amplifier inside the processor
- b. XTAL: crystal quartz or a ceramic resonator
- c. Rf: internal feedback resistor
- d. Rs: external resistor to limit the inverter output current
- e. C1 and C2: are the two external load capacitances

- f. C_s : stray capacitance, is the sum of the microcontroller pin capacitance (OSC_IN and OSC_OUT) and the PCB (a parasitic) capacitance.
- g. gm : Transconductance, where for a small signal is $gm = i_{out} / gm_{crit}$
- h. Gain Margin or (Safety Factor): gain margin = gm / gm_{crit} ,
- i. $gm_{crit\ max} = 4 \times ESR \times (2\pi F)^2 \times (C_0 + CL)^2$, uses max parameters from crystal data sheet.
- j. $gm_{crit\ actual} = gm_{actual} = 4 \times ESR \times (2\pi F)^2 \times (C_0 + CL)^2$, uses actual parameters from crystal measurement.

5. Calculating Gain Margin

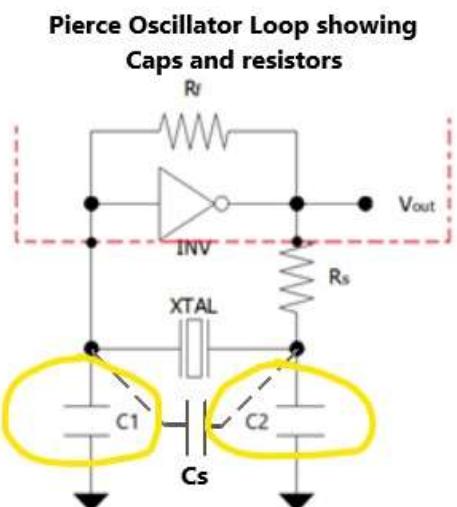
The calculation for Gain Margin: **Gain Margin = gm / gm_{crit}**

This is where gm is the transconductance of the inverter stage in the MCU at the dedicated drive level and $gm_{crit} = (4 \times ESR \times (2\pi F)^2 \times (C_0 + CL)^2)$. These are outlined in the STM32 AN2867 (Ref #2 page 22).

The [ECS Selection Tool](#) has embedded these calculations to allow the user a convenient way to select the KHz crystal options to meet the needs of the LSE oscillator. All the crystals meet the gm_{crit_max} to attain the minimum GM (Gain Margin) of 5, however potential selections will offer even higher GM allowing the user to select different sizes, CL, ESR, Tolerance or Rating to meet application demands.

6. Calculating the External Capacitors for LSE oscillator

Figure 3 – Pierce Oscillator Loop showing external capacitors



The external capacitors are integral part in the design of the oscillator loop. The total capacitance $C_1 // C_2$, C_s and C_{in} and C_{out} of the MCU all combine to a Total Capacitance. This needs to be the same as the Crystal CL for the frequency to be as near as possible to 32.768KHz.

The following formula describes how to calculate CL:

$$CL = \frac{(C_{in} + C_1)(C_2 + C_{out}) + C_s}{C_{in} + C_1 + C_2 + C_{out}}$$

The formula includes the C_{in} and C_{out} of the MCU. The C_{in} is listed in the MCU data sheet, and C_{out} is normally approximately 2x the C_{in} .

The lower the crystal CL, the more impact the Cs (Board Strays) has on the capacitor calculation. As mentioned in Section 4e iii, the low CL can be used in low drive applications, but lower CL has more pullability. When using this formula, it shows how the variability of the external capacitors or board stray capacitance will pull the frequency. When considering external capacitors use COG NPO 1% types to minimise the impact of capacitance change over temperature.

7. Calculating the Drive level

The drive level is an important consideration; over driving can lead to longer term damage to the crystal, so the drive should be within the crystal drive rating found in the manufacturer's specification.

The other less known impact comes from overdriving the sine wave, so that the sine peaks hit the supply rail. As this happens, the small signal loop gain can instantaneously drop to zero. The overall effect is the oscillator amplitude will stabilize when average gain over a cycle is one. The result of this gain averaging is harmonic distortion as seen in jitter of the output waveform.

- If calculating the drive level, I recommend the method taken from the STM32 drive level recommendation (Ref #2 page 15).

DL = $I_{QRMS}^2 \times ESR$, where I_{QRMS} is the RMS AC current. This current can be calculated by measuring the voltage swing at the amplifier input with a low-capacitance oscilloscope probe (no more than 1 pF).

The amplifier input current is negligible with respect to the current through C1, so we can assume that the current through the crystal is equal to the current flowing through C1.

This will be in the uA range, so appropriate measurement equipment should be used. Therefore, the RMS voltage at this point is related to the RMS current by,

$$I_{QRMS} = 2 \pi F \times V_{RMS} \times C_{tot}, \text{ where:}$$

F = crystal frequency

$$V_{RMS} = \frac{V_{pp}}{2\sqrt{2}}, \text{ where } V_{pp} \text{ is the peak-to-peak voltage measured at C1 level}$$

$$C_{tot} = C1 + (Cs / 2) + C_{probe} \text{ where:}$$

- C1 is the external load capacitance at the amplifier input
- Cs is the stray capacitance
- Cprobe is the probe capacitance

$$\text{Therefore } DL = (ESR * \pi * F * C_{tot})^2 \times \frac{(V_{pp})^2}{2}$$

8. Calculating External Rs value

If the drive level exceeds the crystal manufacturer's recommendations, then two options are available to designers using the ECS Selection Tool;

- Look at crystal options with a lower actual gm_{crit} , this will improve the Gain Margin and lower drive current.
- Consider adding a Rs resistor. The role of the Rs resistor is to limit the drive current in the crystal.

- c. An initial estimation of R_s can be obtained by considering the voltage divider formed by R_s and C_2 . Thus, the value of R_s is equal to the reactance of C_2 .
Therefore $R_s = 1 / (2 \pi F C_2)$,
- d. After picking the estimated R_s , then the Gain Margin needs to be recalculated but with R_s added to ESR

$$Gm_{crit} \text{ with } R_s = 4 \times (ESR + R_s) \times (2 \pi F)^2 \times (C_0 + C_L)^2$$

$$\text{Gain Margin} = gm / gmcrit \text{ with } R_s$$

References:

Reference #1 - <https://www.st.com/en/microcontrollers-microprocessors/stm32-32-bit-arm-cortex-mcus.html>

Reference #2 - https://www.st.com/resource/en/application_note/cd00221665-oscillator-design-guide-for-stm8af-al-s-stm32-mcus-and-mpus-stmicroelectronics.pdf

For the ECS Inc. International STM32 MCU Series LSE 32.768 kHz crystal selection tool, click [here](#).

For ECS Inc. International's crystal listings, click [here](#).

For ECS Inc. International's latest product catalog, click [here](#).

For additional ECS Inc. International technical guides, click [here](#).

For additional video resources, click [here](#).